## 2SK3048

#### Silicon N-Channel Power F-MOS FET

#### ■ Features

- Avalanche energy capacity guaranteed
- High-speed switching
- Low ON-resistance
- No secondary breakdown

#### Applications

- Contactless relay
- Diving circuit for a solenoid
- Driving circuit for a motor
- Control equipment
- Switching power supply

#### ■ Absolute Maximum Ratings (T<sub>C</sub> = 25°C)

Parameter		Symbol	Ratings	Unit	
Drain to Source breakdown voltage		V <sub>DSS</sub>	600	V	
Gate to Source voltage		V <sub>GSS</sub>	±30	V	
Drain current	DC	$I_{\mathrm{D}}$	±3	A	
	Pulse	$I_{DP}$	±6	A	
Avalanche energy capacity		EAS*	22.5	mJ	
Allowable power	$T_C = 25^{\circ}C$	D	35	W	
dissipation	Ta = 25°C	$P_{\rm D}$	2		
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature		$T_{stg}$	-55 to +150	°C	

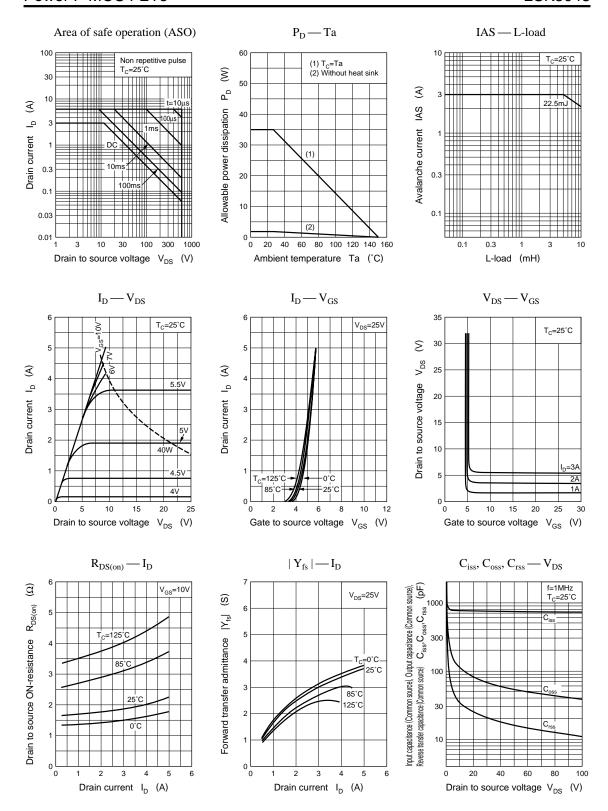
<sup>\*</sup> L = 5mH,  $I_L = 3A$ , 1 pulse

### unit: mm 2.9±0.2 3.0±0.5 15.0±0.5 φ3.2±0.1 2.6±0.1 13.7±0.2 0.55±0.15 0.8±0.1 3 5.08±0.5 1: Gate 2: Drain 3: Source TO-220D Package

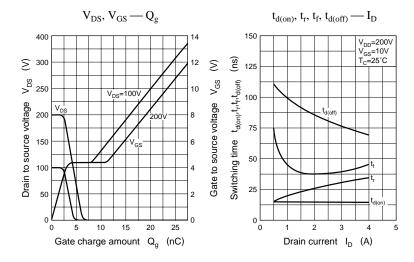
### ■ Electrical Characteristics (T<sub>C</sub> = 25°C)

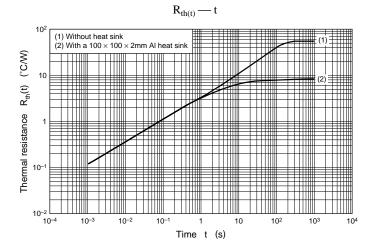
Parameter	Symbol	Conditions	min	typ	max	Unit
Drain to Source cut-off current	$I_{DSS}$	$V_{DS} = 480V, V_{GS} = 0$			100	μΑ
Gate to Source leakage current	$I_{GSS}$	$V_{GS} = \pm 30V, V_{DS} = 0$			±1	μA
Drain to Source breakdown voltage	$V_{DSS}$	$I_D = 1$ mA, $V_{GS} = 0$	600			V
Gate threshold voltage	$V_{th}$	$V_{DS} = 25V, I_D = 1mA$	2		5	V
Drain to Source ON-resistance	R <sub>DS(on)</sub>	$V_{GS} = 10V, I_D = 2A$		1.7	2.5	Ω
Forward transfer admittance	Yfs	$V_{DS} = 25V, I_{D} = 2A$	1.5	2.5		S
Diode forward voltage	$V_{\rm DSF}$	$I_{DR} = 3A, V_{GS} = 0$			-1.5	V
Input capacitance (Common Source)	C <sub>iss</sub>			750		pF
Output capacitance (Common Source)	Coss	$V_{DS} = 20V, V_{GS} = 0, f = 1MHz$		80		pF
Reverse transfer capacitance (Common Source)	C <sub>rss</sub>			25		pF
Turn-on time (delay time)	t <sub>d(on)</sub>			15		ns
Rise time	t <sub>r</sub>	$V_{DD} = 200V, I_D = 2A$		25		ns
Turn-off time (delay time)	$t_{d(off)}$	$V_{GS} = 10V, R_L = 100\Omega$		90		ns
Fall time	t <sub>f</sub>			40		ns

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